TS5A3359
1-Ω SP3T ANALOG SWITCH
5-V/3.3-V SINGLE-CHANNEL 3:1 MULTIPLEXER/DEMULTIPLEXER

SCDS214C−OCTOBER 2005−REVISED JANUARY 2008

FEATURES

- **Isolation in Power-Down Mode, $V_+ = 0$**
- **Specified Break-Before-Make Switching**
- **Low ON-State Resistance (1 Ω)**
- **Control Inputs Are 5.5-V Tolerant**
- **Low Charge Injection**
- **Excellent ON-State Resistance Matching**
- **Low Total Harmonic Distortion (THD)**
- **1.65-V to 5.5-V Single-Supply Operation**
- **Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II**
- **ESD Performance Tested Per JESD 22**
  - **2000-V Human-Body Model (A114-B, Class II)**
  - **1000-V Charged-Device Model (C101)**

APPLICATIONS

- **Cell Phones**
- **PDAs**
- **Portable Instrumentation**
- **Audio and Video Signal Routing**
- **Low-Voltage Data Acquisition Systems**
- **Communication Circuits**
- **Modems**
- **Hard Drives**
- **Computer Peripherals**
- **Wireless Terminals and Peripherals**
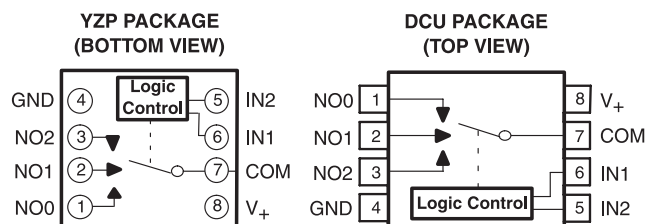
FUNCTION TABLE

IN2	IN1	COM TO NO, NO TO COM
L	L	OFF
L	H	COM = NO0
H	L	COM = NO1
H	H	COM = NO2

DESCRIPTION/ORDERING INFORMATION

The TS5A3359 is a single-pole triple-throw (SP3T) analog switch that is designed to operate from 1.65 V to 5.5 V. The device offers a low ON-state resistance and excellent ON-state resistance matching with the break-before-make feature, to prevent signal distortion during the transferring of a signal from one channel to another. The device has an excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications.

ORDERING INFORMATION

T_A	PACKAGE[1][2]		ORDERABLE PART NUMBER	TOP-SIDE MARKING[3]
−40°C to 85°C	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Tape and reel	TS5A3359YZPR	_ _ _J9_
	VSSOP – DCU	Tape and reel	TS5A3359DCUR	JAL_

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
(3) DCU: The actual top-side marking has one additional character that designates the assembly/test site.
YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

TS5A3359
1-Ω SP3T ANALOG SWITCH
5-V/3.3-V SINGLE-CHANNEL 3:1 MULTIPLEXER/DEMULTIPLEXER

SCDS214C−OCTOBER 2005−REVISED JANUARY 2008

Summary of Characteristics[1]

Configuration	Triple 3:1 Multiplexer/ Demultiplexer (1 × SP3T)
Number of channels	1
ON-state resistance (r_{on})	1.1 Ω
ON-state resistance match (Δr_{on})	0.1 Ω
ON-state resistance flatness ($r_{on(flat)}$)	0.15 Ω
Turn-on/turn-off time (t_{ON}/t_{OFF})	40 ns/35 ns
Break-before-make time (t_{BBM})	1 ns
Charge injection (Q_C)	40 pC
Bandwidth (BW)	100 MHz
OFF isolation (O_{ISO})	−65 dB at 10 MHz
Crosstalk (X_{TALK})	−66 dB at 10 MHz
Total harmonic distortion (THD)	0.01%
Leakage current ($I_{COM(OFF)}/I_{NO(OFF)}$)	±20 µA
Power supply current (I_+)	0.1 µA
Package options	8-pin DCU or YZP

(1) V_+ = 5 V, T_A = 25°C

ABSOLUTE MINIMUM AND MAXIMUM RATINGS[1][2]

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_+	Supply voltage range[3]		−0.5	6.5	V
V_{NO} V_{COM}	Analog voltage range[3][4][5]		−0.5	V_+ + 0.5	V
I_K	Analog port diode current	V_{NO}, V_{COM} < 0	−50		mA
I_{NO} I_{COM}	On-state switch current	V_{NO}, V_{COM} = 0 to V_+	−200	200	mA
			−400	400	
V_I	Digital input voltage range[3][4]		−0.5	6.5	V
I_{IK}	Digital input clamp current	V_I < 0	−50		mA
I_+	Continuous current through V_+			100	mA
I_{GND}	Continuous current through GND		−100	100	mA
T_{stg}	Storage temperature range		−65	150	°C

(1)   Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
(2)   The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(3)   All voltages are with respect to ground, unless otherwise specified.
(4)   The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(5)   This value is limited to 5.5 V maximum.

PACKAGE THERMAL IMPEDANCE

				UNIT
θ_{JA}	Package thermal impedance[1]	DCU package	227	°C/W
		YZP package	140	

(1)   The package thermal impedance is calculated in accordance with JESD 51-7.

ELECTRICAL CHARACTERISTICS FOR 5-V SUPPLY[1]

V_+ = 4.5 V to 5.5 V, T_A = −40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V_{COM}, V_{NO}					0		V_+	V
Peak ON resistance	r_{peak}	$0 \le (V_{NO}) \le V_+$, I_{COM} = −100 mA,	Switch ON, See Figure 19	25°C	4.5 V		0.8	1.1	Ω
				Full				1.5	
ON-state resistance	r_{on}	V_{NO} = 2.5 V, I_{COM} = −100 mA,	Switch ON, See Figure 19	25°C	4.5 V		0.7	0.9	Ω
				Full				1.1	
ON-state resistance match between channels	Δr_{on}	V_{NO} = 2.5 V, I_{COM} = −100 mA,	Switch ON, See Figure 19	25°C	4.5 V		0.1	0.1	Ω
				Full				0.1	
ON-state resistance flatness	$r_{on(flat)}$	$0 \le (V_{NO}) \le V_+$, I_{COM} = −100 mA,	Switch ON, See Figure 19	25°C	4.5 V		0.15		Ω
		V_{NO} = 1 V, 1.5 V, 2.5 V, I_{COM} = −100 mA,	Switch ON, See Figure 19	25°C			0.1	0.25	
				Full				0.25	
NO OFF leakage current	$I_{NO(OFF)}$	V_{NO} = 1 V or 4.5 V, V_{COM} = 1 V to 4.5 V,	Switch OFF, See Figure 20	25°C	5.5 V	−20	5	20	nA
				Full		−150		150	
	$I_{NO(PWROFF)}$	V_{NO} = 0 to 5.5 V, V_{COM} = 5.5 V to 0,	Switch OFF, See Figure 20	25°C	0 V	−1	0.8	1	µA
				Full		−25		25	
NO ON leakage current	$I_{NO(ON)}$	V_{NO} = 1 V or 4.5 V, V_{COM} = Open,	Switch ON, See Figure 20	25°C	5.5 V	−30	5	30	nA
				Full		−220		220	
COM OFF leakage current	$I_{COM(OFF)}$	V_{NO} = 4.5 V or 1 V, V_{COM} = 1 V or 4.5 V,	Switch OFF, See Figure 20	25°C	5.5 V	−25	8	25	nA
				Full		−250		250	
	$I_{COM(PWROFF)}$	V_{COM} = 0 to 5.5 V, V_{NO} = 5.5 V to 0,	Switch OFF, See Figure 20	25°C	0 V	−8	0.1	8	µA
				Full		−50		50	
COM ON leakage current	$I_{COM(ON)}$	V_{NO} = Open, V_{COM} = 1 V or 4.5 V,	Switch ON, See Figure 20	25°C	5.5 V	−30	5	30	nA
				Full		−220		220	
Digital Control Inputs (IN1, IN2)[2]									
Input logic high	V_{IH}			Full		2.4		5.5	V
Input logic low	V_{IL}			Full		0		0.8	V
Input leakage current	I_{IH}, I_{IL}	V_I = 5.5 V or 0		25°C	5.5 V	−2		2	µA
				Full		−20		20	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

TS5A3359
1-Ω SP3T ANALOG SWITCH
5-V/3.3-V SINGLE-CHANNEL 3:1 MULTIPLEXER/DEMULTIPLEXER

SCDS214C−OCTOBER 2005−REVISED JANUARY 2008

TEXAS INSTRUMENTS
www.ti.com

ELECTRICAL CHARACTERISTICS FOR 5-V SUPPLY (continued)

V_+ = 4.5 V to 5.5 V, T_A = −40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	t_{ON}	$V_{COM} = V_+$, R_L = 50 Ω,	C_L = 35 pF, See Figure 23	25°C	5 V	1	2.5	21	ns
				Full	4.5 V to 5.5 V	1		23.5	
Turn-off time	t_{OFF}	$V_{COM} = V_+$, R_L = 50 Ω,	C_L = 35 pF, See Figure 23	25°C	5 V	1	6	10.5	ns
				Full	4.5 V to 5.5 V	1		12	
Break-before-make time	t_{BBM}	$V_{NO} = V_+$, R_L = 50 Ω,	C_L = 35 pF, See Figure 24	25°C	5 V	0.5	8.5	18	ns
				Full	4.5 V to 5.5 V	0.5		23	
Charge injection	Q_C	V_{GEN} = 0, R_{GEN} = 0,	C_L = 1 nF, See Figure 28	25°C	5 V		20		pC
NO OFF capacitance	$C_{NO(OFF)}$	$V_{NO} = V_+$ or GND, Switch OFF,	See Figure 22	25°C	5 V		18		pF
COM OFF capacitance	$C_{COM(OFF)}$	$V_{COM} = V_+$ or GND, Switch OFF,	See Figure 22	25°C	2.5 V		54		pF
NO ON capacitance	$C_{NO(ON)}$	$V_{NO} = V_+$ or GND, Switch ON,	See Figure 22	25°C	5 V		78		pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch ON,	See Figure 22	25°C	5 V		78		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND,	See Figure 22	25°C	5 V		2.5		pF
Bandwidth	BW	R_L = 50 Ω, Switch ON,	See Figure 25	25°C	5 V		75		MHz
OFF isolation	O_{ISO}	R_L = 50 Ω, f = 1 MHz ,	Switch OFF, See Figure 26	25°C	5 V		−64		dB
Crosstalk	X_{TALK}	R_L = 50 Ω, f = 1 MHz ,	Switch ON, See Figure 27	25°C	5 V		−64		dB
Total harmonic distortion	THD	R_L = 600 Ω, C_L = 50 pF,	f = 20 Hz to 20 kHz, See Figure 29	25°C	5 V		0.005		%
Supply									
Positive supply current	I_+	$V_I = V_+$ or GND,	Switch ON or OFF	25°C	5.5 V		16	50	nA
				Full				1200	

Product Folder Link(s): *TS5A3359*

ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY[1]

V_+ = 3 V to 3.6 V, T_A = −40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V_{COM}, V_{NO}					0		V_+	V
Peak ON resistance	r_{peak}	$0 \leq (V_{NO}) \leq V_+$, I_{COM} = −100 mA,	Switch ON, See Figure 19	25°C	3 V		1.3	1.6	Ω
				Full				2	
ON-state resistance	r_{on}	V_{NO} = 2 V, I_{COM} = −100 mA,	Switch ON, See Figure 19	25°C	3 V		1.2	1.6	Ω
				Full				1.8	
ON-state resistance match between channels	Δr_{on}	V_{NO} = 2 V, 0.8 V, I_{COM} = −100 mA,	Switch ON, See Figure 19	25°C	3 V		0.1	0.15	Ω
				Full				0.15	
ON-state resistance flatness	$r_{on(flat)}$	$0 \leq (V_{NO}) \leq V_+$, I_{COM} = −100 mA,	Switch ON, See Figure 19	25°C	3 V		0.2		Ω
		V_{NO} = 2 V, 0.8 V, I_{COM} = −100 mA,	Switch ON, See Figure 19	25°C			0.2	0.35	
				Full				0.35	
NO OFF leakage current	$I_{NO(OFF)}$	V_{NO} = 1 V or 3 V, V_{COM} = 1 V to 3 V,	Switch OFF, See Figure 20	25°C	3.6 V	−15	3	15	nA
				Full		−30		30	
	$I_{NO(PWROFF)}$	V_{NO} = 0 to 3.6 V, V_{COM} = 3.6 V to 0,	Switch OFF, See Figure 20	25°C	0 V	−1	0.2	1	μA
				Full		−10		10	
NO ON leakage current	$I_{NO(ON)}$	V_{NO} = 1 V or 3 V, V_{COM} = Open,	Switch ON, See Figure 20	25°C	3.6 V	−15	3	15	nA
				Full		−40		40	
COM OFF leakage current	$I_{COM(OFF)}$	V_{NO} = 0 V to 3.6 V, V_{COM} = 1 V or V_{NO} = 3.6 V to 0, V_{COM} = 3 V,	Switch OFF, See Figure 20	25°C	3.6 V	−15	3	15	nA
				Full		−75		75	
	$I_{COM(PWROFF)}$	V_{COM} = 0 to 3.6 V, V_{NO} = 3.6 V to 0,	Switch OFF, See Figure 20	25°C	0 V	−1	0.2	1	μA
				Full		−20		20	
COM ON leakage current	$I_{COM(ON)}$	V_{NO} = Open, V_{COM} = 1 V or 3 V,	Switch ON, See Figure 20	25°C	3.6 V	−15	4	15	nA
				Full		−40		40	
Digital Control Inputs (IN1, IN2)[2]									
Input logic high	V_{IH}			Full		2		5.5	V
Input logic low	V_{IL}			Full		0		0.8	V
Input leakage current	I_{IH}, I_{IL}	V_I = 5.5 V or 0		25°C	3.6 V	−2		2	nA
				Full		−20		20	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

TS5A3359
1-Ω SP3T ANALOG SWITCH
5-V/3.3-V SINGLE-CHANNEL 3:1 MULTIPLEXER/DEMULTIPLEXER
SCDS214C−OCTOBER 2005−REVISED JANUARY 2008

TEXAS INSTRUMENTS
www.ti.com

ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY (continued)

V_+ = 3 V to 3.6 V, T_A = −40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	t_{ON}	$V_{COM} = V_+$, $R_L = 50\ \Omega$,	C_L = 35 pF, See Figure 23	25°C	3.3 V	1	16	30.5	ns
				Full	3 V to 3.6 V	1		34	
Turn-off time	t_{OFF}	$V_{COM} = V_+$, $R_L = 50\ \Omega$,	C_L = 35 pF, See Figure 23	25°C	3.3 V	1	6	11.5	ns
				Full	3 V to 3.6 V	1		12.5	
Break-before-make time	t_{BBM}	$V_{NO} = V_+$, $R_L = 50\ \Omega$,	C_L = 35 pF, See Figure 24	25°C	3.3 V	0.5	13	26	ns
				Full	3 V to 3.6 V	0.5		30	
Charge injection	Q_C	$V_{GEN} = 0$, $R_{GEN} = 0$,	C_L = 1 nF, See Figure 28	25°C	3.3 V		12		pC
NO OFF capacitance	$C_{NO(OFF)}$	$V_{NO} = V_+$ or GND, Switch OFF,	See Figure 22	25°C	3.3 V		18		pF
COM OFF capacitance	$C_{COM(OFF)}$	$V_{COM} = V_+$ or GND, Switch OFF,	See Figure 22	25°C	3.3 V		55		pF
NO ON capacitance	$C_{NO(ON)}$	$V_{NO} = V_+$ or GND, Switch ON,	See Figure 22	25°C	3.3 V		78		pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch ON,	See Figure 22	25°C	3.3 V		78		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND,	See Figure 22	25°C	3.3 V		2.5		pF
Bandwidth	BW	$R_L = 50\ \Omega$, Switch ON,	See Figure 25	25°C	3.3 V		73		MHz
OFF isolation	O_{ISO}	$R_L = 50\ \Omega$, f = 1 MHz,	Switch OFF, See Figure 26	25°C	3.3 V		−64		dB
Crosstalk	X_{TALK}	$R_L = 50\ \Omega$, f = 1 MHz,	Switch ON, See Figure 27	25°C	3.3 V		−64		dB
Total harmonic distortion	THD	$R_L = 600\ \Omega$, C_L = 50 pF,	f = 20 Hz to 20 kHz, See Figure 29	25°C	3.3 V		0.010		%
Supply									
Positive supply current	I_+	$V_I = V_+$ or GND,	Switch ON or OFF	25°C	3.6 V		2	20	nA
				Full				350	

Product Folder Link(s): *TS5A3359*

ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY[1]

V_+ = 2.3 V to 2.7 V, T_A = −40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V_{COM}, V_{NO}					0		V_+	V
Peak ON resistance	r_{peak}	$0 ≤ (V_{NO}) ≤ V_+$, I_{COM} = −8 mA,	Switch ON, See Figure 19	25°C	2.3 V		1.8	2.5	Ω
				Full				2.7	
ON-state resistance	r_{on}	V_{NO} = 1.8 V, I_{COM} = −8 mA,	Switch ON, See Figure 19	25°C	2.3 V		1.5	2	Ω
				Full				2.4	
ON-state resistance match between channels	$Δr_{on}$	V_{NO} = 1.8 V, I_{COM} = −8 mA,	Switch ON, See Figure 19	25°C	2.3 V			0.2	Ω
				Full				0.2	
ON-state resistance flatness	$r_{on(flat)}$	$0 ≤ (V_{NO}) ≤ V_+$, I_{COM} = −8 mA,	Switch ON, See Figure 19	25°C	2.3 V		0.6		Ω
		V_{NO} = 0.8 V, 1.8 V I_{COM} = −8 mA,	Switch ON, See Figure 19	25°C			0.6	1	
				Full				1	
NO OFF leakage current	$I_{NO(OFF)}$	V_{NO} = 0.5 V or 2.3 V, V_{COM} = 0.5 V to 2.3 V,	Switch OFF, See Figure 20	25°C	2.7 V	−15	3	15	nA
				Full		−30		30	
	$I_{NO(PWROFF)}$	V_{NO} = 0 to 2.7 V, V_{COM} = 2.7 V to 0,	Switch OFF, See Figure 20	25°C	0 V	−1	0.1	1	µA
				Full		−10		10	
NO ON leakage current	$I_{NO(ON)}$	V_{NO} = 0.5 V or 2.3 V, V_{COM} = Open,	Switch ON, See Figure 20	25°C	2.7 V	−15	3	15	nA
				Full		−35		35	
COM OFF leakage current	$I_{COM(OFF)}$	V_{NO} = 0.3 V to 2.3 V, V_{COM} = 0.5 V or 2.3 V,	Switch OFF, See Figure 20	25°C	2.7 V	−15	3	15	nA
				Full		−60		60	
	$I_{COM(PWROFF)}$	V_{COM} = 0 to 2.7 V, V_{NO} = 2.7 V to 0,	Switch OFF, See Figure 20	25°C	0 V	−1	0.1	1	µA
				Full		−10		10	
COM ON leakage current	$I_{COM(ON)}$	V_{NO} = Open, V_{COM} = 0.5 V or 2.2 V,	Switch ON, See Figure 20	25°C	2.7 V	−15	3.5	15	nA
				Full		−40		40	
Digital Control Inputs (IN1, IN2)[2]									
Input logic high	V_{IH}			Full		1.8		5.5	V
Input logic low	V_{IL}			Full		0		0.6	V
Input leakage current	I_{IH}, I_{IL}	V_I = 5.5 V or 0		25°C	2.7 V	1		1	nA
				Full		10		10	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

TS5A3359
1-Ω SP3T ANALOG SWITCH
5-V/3.3-V SINGLE-CHANNEL 3:1 MULTIPLEXER/DEMULTIPLEXER
SCDS214C−OCTOBER 2005−REVISED JANUARY 2008

TEXAS
INSTRUMENTS
www.ti.com

ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY (continued)

V_+ = 2.3 V to 2.7 V, T_A = −40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	t_{ON}	V_{COM} = V_+, R_L = 50 Ω,	C_L = 35 pF, See Figure 23	25°C	2.5 V	2	4.5	43	ns
				Full	2.3 V to 2.7 V	2		47.5	
Turn-off time	t_{OFF}	V_{COM} = V_+, R_L = 50 Ω,	C_L = 35 pF, See Figure 23	25°C	2.5 V	2	8.5	11	ns
				Full	2.3 V to 2.7 V	2		12.5	
Break-before-make time	t_{BBM}	V_{NO} = V_+, R_L = 50 Ω,	C_L = 35 pF, See Figure 24	25°C	2.5 V	0.5	18.5	38.5	ns
				Full	2.3 V to 2.7 V	0.5		43	
Charge injection	Q_C	V_{GEN} = 0, R_{GEN} = 0,	C_L = 1 nF, See Figure 28	25°C	2.5 V		8		pC
NO OFF capacitance	$C_{NO(OFF)}$	V_{NO} = V_+ or GND, Switch OFF,	See Figure 22	25°C	2.5 V		18.5		pF
COM OFF capacitance	$C_{COM(OFF)}$	V_{COM} = V_+ or GND, Switch OFF,	See Figure 22	25°C	2.5 V		55		pF
NO ON capacitance	$C_{NO(ON)}$	V_{NO} = V_+ or GND, Switch ON,	See Figure 22	25°C	2.5 V		78		pF
COM ON capacitance	$C_{COM(ON)}$	V_{COM} = V_+ or GND, Switch ON,	See Figure 22	25°C	2.5 V		78		pF
Digital input capacitance	C_I	V_I = V_+ or GND,	See Figure 22	25°C	2.5 V		3		pF
Bandwidth	BW	R_L = 50 Ω, Switch ON,	See Figure 25	25°C	2.5 V		73		MHz
OFF isolation	O_{ISO}	R_L = 50 Ω, f = 1 MHz,	Switch OFF, See Figure 26	25°C	2.5 V		−64		dB
Crosstalk	X_{TALK}	R_L = 50 Ω, f = 1 MHz,	Switch ON, See Figure 27	25°C	2.5 V		−64		dB
Total harmonic distortion	THD	R_L = 600 Ω, C_L = 50 pF,	f = 20 Hz to 20 kHz, See Figure 29	25°C	2.5 V		0.030		%
Supply									
Positive supply current	I_+	V_I = V_+ or GND,	Switch ON or OFF	25°C	2.7 V		1	10	nA
				Full				250	

Product Folder Link(s): *TS5A3359*

ELECTRICAL CHARACTERISTICS FOR 1.8-V SUPPLY[1]

V_+ = 1.65 V to 1.95 V, T_A = −40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V_{COM}, V_{NO}					0		V_+	V
Peak ON resistance	r_{peak}	$0 \le (V_{NO}) \le V_+$, I_{COM} = −2 mA,	Switch ON, See Figure 19	25°C	1.65 V		5		Ω
				Full				30	
ON-state resistance	r_{on}	V_{NO} = 1.5 V, I_{COM} = −2 mA,	Switch ON, See Figure 19	25°C	1.65 V		2	2.5	Ω
				Full				3.5	
ON-state resistance match between channels	Δr_{on}	V_{NO} = 1.5 V, I_{COM} = −2 mA,	Switch ON, See Figure 19	25°C	1.65 V		0.15	0.4	Ω
				Full				0.4	
ON-state resistance flatness	$r_{on(flat)}$	$0 \le (V_{NO}) \le V_+$, I_{COM} = −2 mA,	Switch ON, See Figure 19	25°C	1.65 V		5		Ω
		V_{NO} = 0.6 V, 1.5 V I_{COM} = −2 mA,	Switch ON, See Figure 19	25°C			4.5		
				Full			5		
NO OFF leakage current	$I_{NO(OFF)}$	V_{NO} =0.3 V or 1.65 V, V_{COM} = 0.3 V to 1.65 V,	Switch OFF, See Figure 20	25°C	1.95 V	−15	3	15	nA
				Full		−30		30	
	$I_{NO(PWROFF)}$	V_{NO} = 0 to 1.95 V, V_{COM} = 1.95 V to 0,	Switch OFF, See Figure 20	25°C	0 V	−1	0.1	1	μA
				Full		−15		15	
NO ON leakage current	$I_{NO(ON)}$	V_{NO} =0.3 V or 1.65 V, V_{COM} = Open,	Switch ON, See Figure 20	25°C	1.95 V	−15	3	15	nA
				Full		−30		30	
COM OFF leakage current	$I_{COM(OFF)}$	V_{NO} = 0.3 V to 1.65 V, V_{COM} =0.3 V or 1.65 V,	Switch OFF, See Figure 20	25°C	1.95 V	−15	3	15	nA
				Full		−50		50	
	$I_{COM(PWROFF)}$	V_{COM} = 0 to 1.95 V, V_{NO} = 1.95 V to 0,	Switch OFF, See Figure 20	25°C	0 V	−1	0.1	1	μA
				Full		−10		10	
COM ON leakage current	$I_{COM(ON)}$	V_{NO} = Open, V_{COM} = 0.3 V or 1.65 V,	Switch ON, See Figure 20	25°C	1.95 V	−15	3	15	nA
				Full		−30		30	
Digital Control Inputs (IN1, IN2)[2]									
Input logic high	V_{IH}			Full		1.5		5.5	V
Input logic low	V_{IL}			Full		0		0.6	V
Input leakage current	I_{IH}, I_{IL}	V_I = 5.5 V or 0		25°C	1.95 V	−2		2	nA
				Full		−20		20	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

TEXAS INSTRUMENTS
www.ti.com

ELECTRICAL CHARACTERISTICS FOR 1.8-V SUPPLY (continued)

V_+ = 1.65 V to 1.95 V, T_A = −40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	t_{ON}	V_{COM} = V_+, R_L = 50 Ω,	C_L = 35 pF, See Figure 23	25°C	1.8 V	3	38.5	85	ns
				Full	1.65 V to 1.95 V	3		90	
Turn-off time	t_{OFF}	V_{COM} = V_+, R_L = 50 Ω,	C_L = 35 pF, See Figure 23	25°C	1.8 V	2	8.5	16	ns
				Full	1.65 V to 1.95 V	2		18	
Break-before-make time	t_{BBM}	V_{NO} = V_+, R_L = 50 Ω,	C_L = 35 pF, See Figure 24	25°C	1.8 V	1	33	75	ns
				Full	1.65 V to 1.95 V	1		80	
Charge injection	Q_C	V_{GEN} = 0, R_{GEN} = 0,	C_L = 1 nF, See Figure 28	25°C	1.8 V			5	pC
NO OFF capacitance	$C_{NO(OFF)}$	V_{NO} = V_+ or GND, Switch OFF,	See Figure 22	25°C	1.8 V		18.5		pF
COM OFF capacitance	$C_{COM(OFF)}$	V_{COM} = V_+ or GND, Switch OFF,	See Figure 22	25°C	1.8 V		55		pF
NO ON capacitance	$C_{NO(ON)}$	V_{NO} = V_+ or GND, Switch ON,	See Figure 22	25°C	1.8 V		78		pF
COM ON capacitance	$C_{COM(ON)}$	V_{COM} = V_+ or GND, Switch ON,	See Figure 22	25°C	1.8 V		78		pF
Digital input capacitance	C_I	V_I = V_+ or GND,	See Figure 22	25°C	1.8 V		3		pF
Bandwidth	BW	R_L = 50 Ω, Switch ON,	See Figure 25	25°C	1.8 V		73		MHz
OFF isolation	O_{ISO}	R_L = 50 Ω, f = 1 M Hz ,	Switch OFF, See Figure 26	25°C	1.8 V		−64		dB
Crosstalk	X_{TALK}	R_L = 50 Ω, f = 1 MHz,	Switch ON, See Figure 27	25°C	1.8 V		−64		dB
Total harmonic distortion	THD	R_L = 600 Ω, C_L = 50 pF,	f = 20 Hz to 20 kHz, See Figure 29	25°C	1.8 V		0.080		%
Supply									
Positive supply current	I_+	V_I = V_+ or GND,	Switch ON or OFF	25°C	1.95 V		1		nA
				Full				200	

Product Folder Link(s): *TS5A3359*

TYPICAL PERFORMANCE
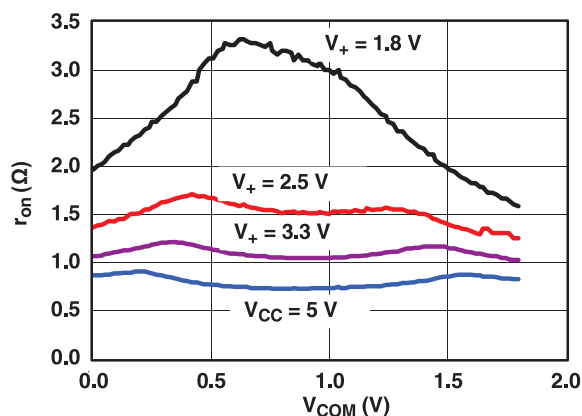
Figure 1. r_{on} vs V_{COM}

Figure 2. r_{on} vs V_{COM} (V_+ = 3.3 V)

Figure 3. r_{on} vs V_{COM} (V_+ = 5 V)

Figure 4. Leakage Current vs Temperature

Figure 5. Leakage Current vs Temperature
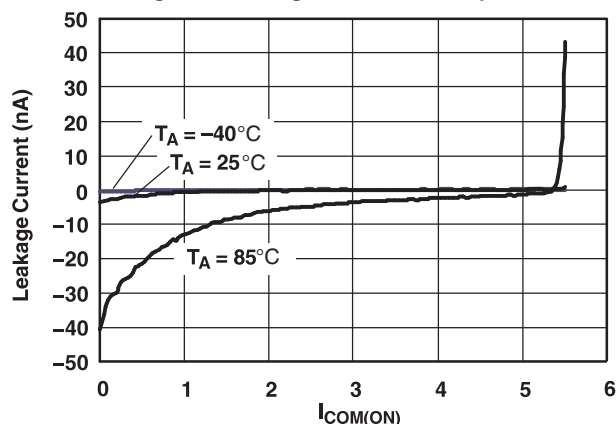
Figure 6. Leakage Current vs Temperature

Product Folder Link(s): TS5A3359

TEXAS INSTRUMENTS
www.ti.com

TYPICAL PERFORMANCE (continued)
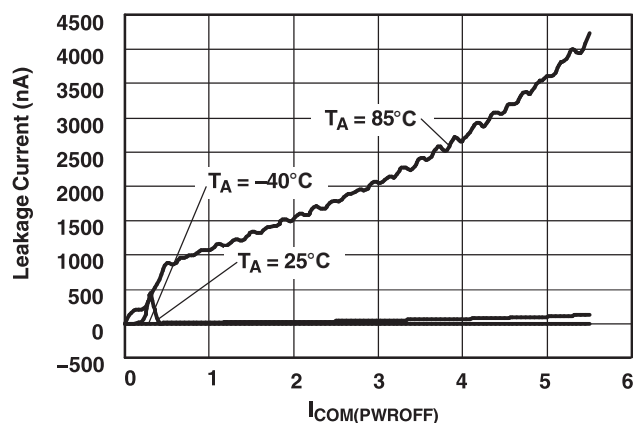
Figure 7. Leakage Current vs Temperature

Figure 8. Charge Injection (Q_C) vs V_{COM}

Figure 9. t_{ON} and t_{OFF} vs Supply Voltage
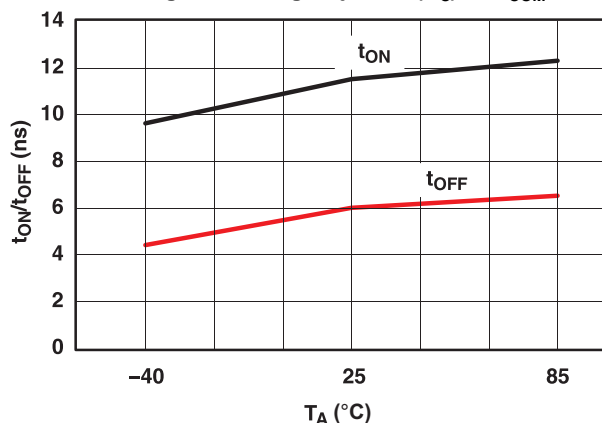
Figure 10. t_{ON} and t_{OFF} vs Temperature

Figure 11. Logic-Level Threshold vs V_+

Figure 12. Bandwidth (V_+ = 5 V)

Product Folder Link(s): *TS5A3359*
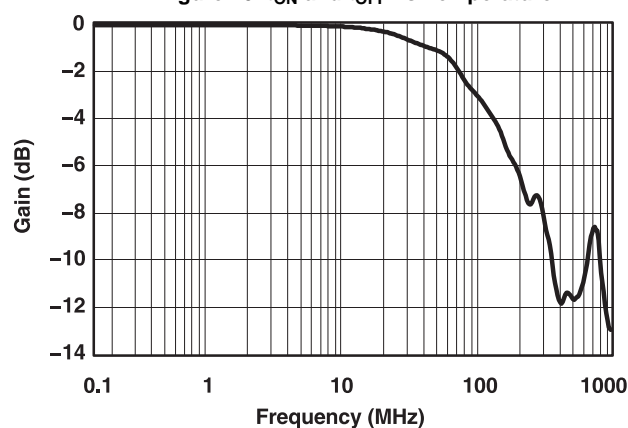
TYPICAL PERFORMANCE (continued)
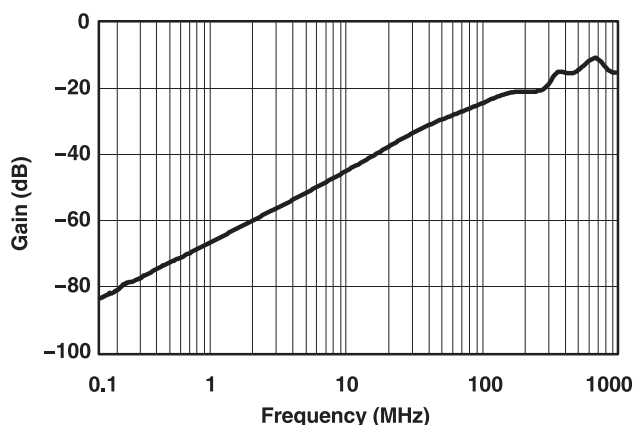
Figure 13. OFF Isolation vs Crosstalk
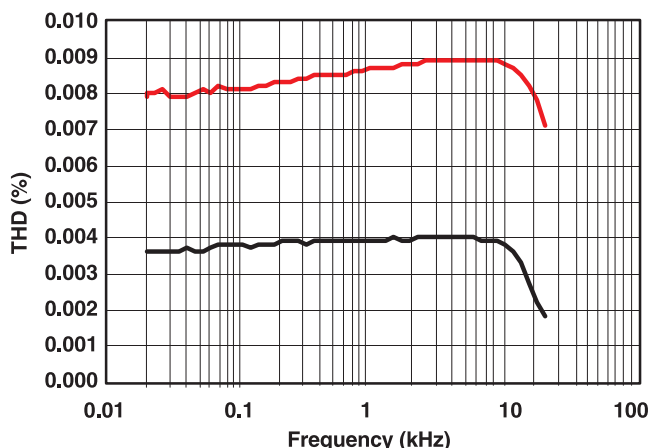
Figure 14. Total Harmonic Distortion vs Frequency
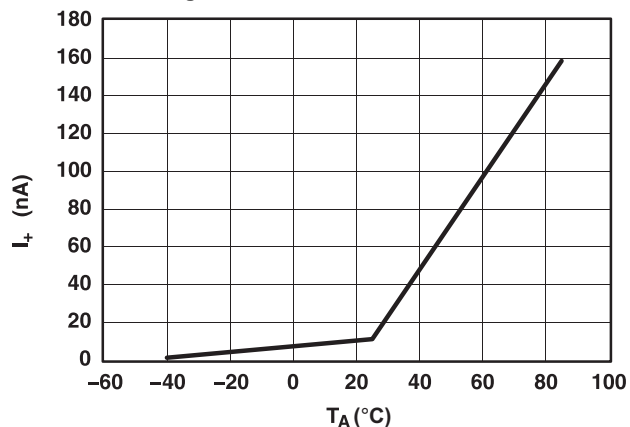
Figure 15. Power-Supply Current vs Temperature (V$_+$ = 5)
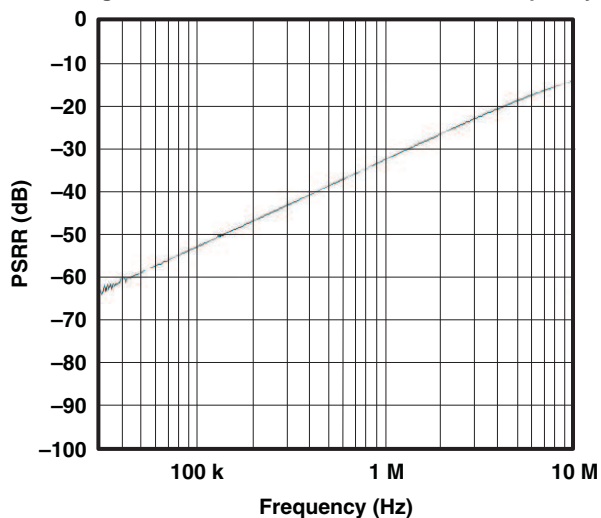
Figure 16. COM Port to NO2 PSRR,
IN1 = V$_{CC}$, IN2 = V$_{CC}$ (V$_{CC}$ = 5 V)
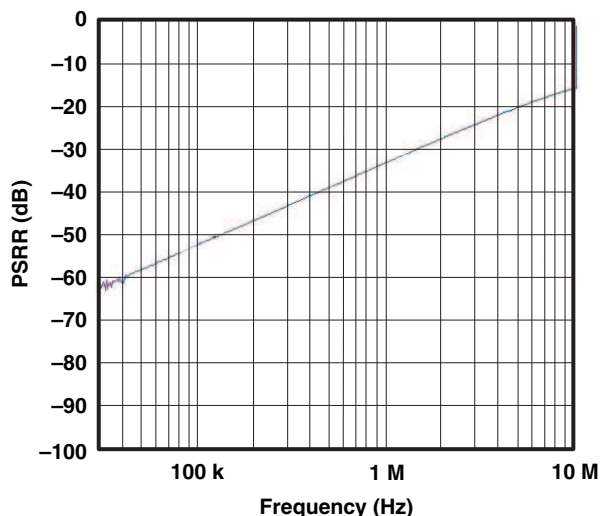
Figure 17. COM Port to NO0 PSRR,
IN1 = V$_{CC}$, IN2 = V$_{CC}$ (V$_{CC}$ = 5 V)
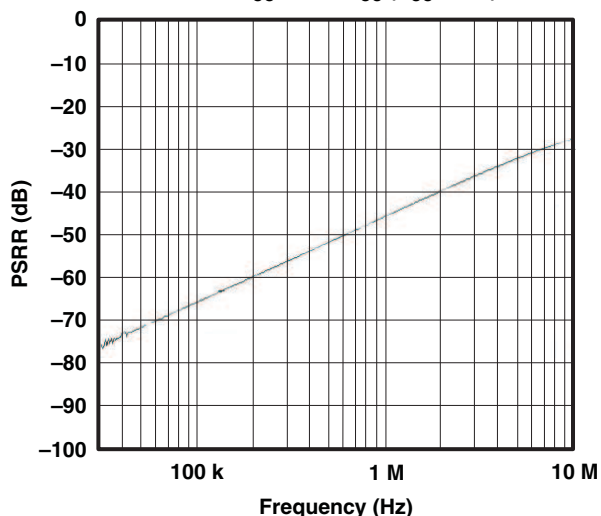
Figure 18. COM Port Hi-Z PSRR,
IN1 = 0 V, IN2 = 0 V (V$_{CC}$ = 5 V)

Product Folder Link(s): *TS5A3359*

TS5A3359
1-Ω SP3T ANALOG SWITCH
5-V/3.3-V SINGLE-CHANNEL 3:1 MULTIPLEXER/DEMULTIPLEXER

SCDS214C−OCTOBER 2005−REVISED JANUARY 2008

TEXAS INSTRUMENTS
www.ti.com

PIN DESCRIPTION

PIN NO.	NAME	DESCRIPTION
1	NO0	Normally open
2	NO1	Normally open
3	NO2	Normally open
4	GND	Digital ground
5	IN2	Digital control to connect COM to NO
6	IN1	Digital control to connect COM to NO
7	COM	Common
8	V$_+$	Power supply

PARAMETER DESCRIPTION

SYMBOL	DESCRIPTION
V_{COM}	Voltage at COM
V_{NO}	Voltage at NO
r_{on}	Resistance between COM and NC or COM and NO ports when the channel is ON
r_{peak}	Peak on-state resistance over a specified voltage range
Δr_{on}	Difference of r_{on} between channels in a specific device
$r_{on(flat)}$	Difference between the maximum and minimum value of r_{on} in a channel over the specified range of conditions
$I_{NO(OFF)}$	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state
$I_{NO(PWROFF)}$	Leakage current measured at the NO port during the power-down condition, $V_+ = 0$.
$I_{NO(ON)}$	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) open
$I_{COM(ON)}$	Leakage current measured at the COM port, with the corresponding channel (COM to NO or COM to NC) in the ON state and the output (NC or NO) open
$I_{COM(OFF)}$	Leakage current measured at the COM port during the power-down condition, $V_+ = 0$
$I_{COM(PWROFF)}$	Leakage current measured at the COM port during the power-down condition, $V_+ = 0$.
V_{IH}	Minimum input voltage for logic high for the control input (IN)
V_{IL}	Maximum input voltage for logic low for the control input (IN)
V_I	Voltage at the control input (IN)
I_{IH}, I_{IL}	Leakage current measured at the control input (IN)
t_{ON}	Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning ON.
t_{OFF}	Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning OFF.
t_{BBM}	Break-before-make time. This parameter is measured under the specified range of conditions and by the propagation delay between the output of two adjacent analog channels (NC and NO) when the control signal changes state.
Q_C	Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NO or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_C = C_L \times \Delta V_{COM}$, C_L is the load capacitance and ΔV_{COM} is the change in analog output voltage.
$C_{NO(OFF)}$	Capacitance at the NO port when the corresponding channel (NO to COM) is OFF
$C_{NO(ON)}$	Capacitance at the NO port when the corresponding channel (NO to COM) is ON
$C_{COM(ON)}$	Capacitance at the COM port when the corresponding channel (COM to NO) is ON
$C_{COM(OFF)}$	Capacitance at the COM port when the corresponding channel (COM to NO) is OFF
C_I	Capacitance of control input (IN)
O_{ISO}	OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NC to COM or NO to COM) in the OFF state.
X_{TALK}	Crosstalk is a measurement of unwanted signal coupling from an ON channel to an OFF channel (NC to NO or NO to NC). This is measured in a specific frequency and in dB.
BW	Bandwidth of the switch. This is the frequency in which the gain of an ON channel is −3 dB below the DC gain.

Product Folder Link(s): *TS5A3359*

PARAMETER DESCRIPTION (continued)

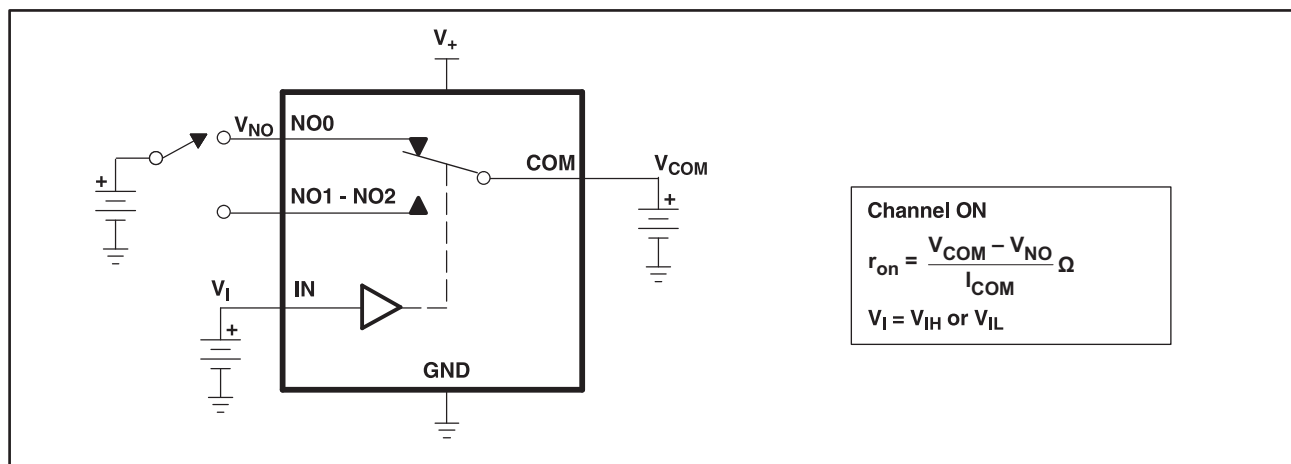| SYMBOL	DESCRIPTION
THD	Total harmonic distortion describes the signal distortion caused by the analog switch. This is defined as the ratio of root mean square (RMS) value of the second, third, and higher harmonic to the absolute magnitude of the fundamental harmonic.
I_+	Static power-supply current with the control (IN) pin at V_+ or GND

Submit Documentation Feedback   15

Product Folder Link(s): *TS5A3359*

TS5A3359
1-Ω SP3T ANALOG SWITCH
5-V/3.3-V SINGLE-CHANNEL 3:1 MULTIPLEXER/DEMULTIPLEXER
SCDS214C−OCTOBER 2005−REVISED JANUARY 2008

TEXAS
INSTRUMENTS
www.ti.com

PARAMETER MEASURMENT INFORMATION

Channel ON

$$r_{on} = \frac{V_{COM} - V_{NO}}{I_{COM}} \, \Omega$$

$V_I = V_{IH}$ or V_{IL}

Figure 19. ON-State Resistance (r_{on})

OFF-State Leakage Current
Channel OFF
$V_I = V_{IH}$ or V_{IL}
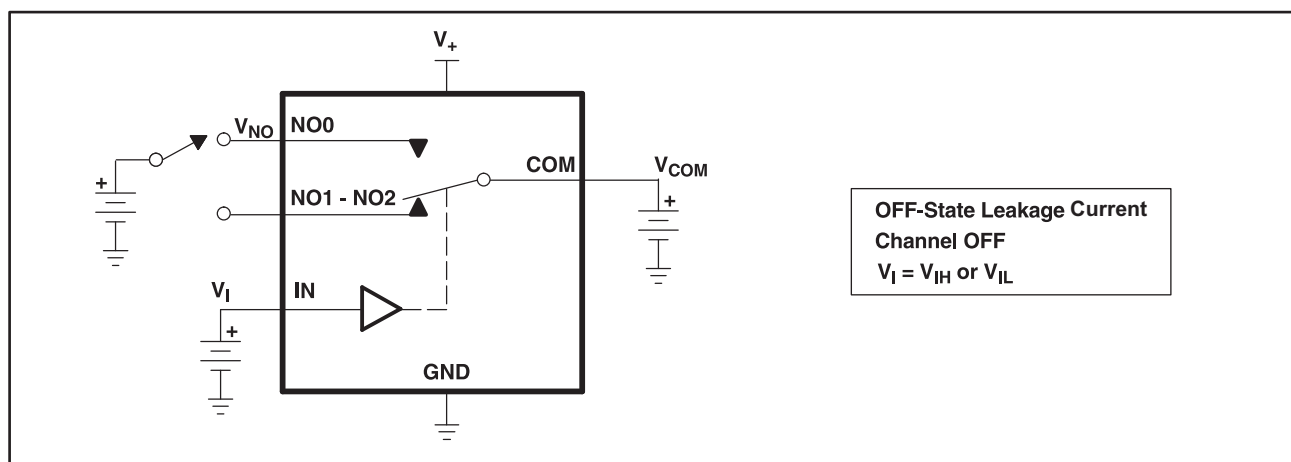
Figure 20. OFF-State Leakage Current ($I_{NC(OFF)}$, $I_{NO(OFF)}$, $I_{NO(PWROFF)}$, $I_{COM(OFF)}$, $I_{COM(PWROFF)}$)

ON-State Leakage Current
Channel ON
$V_I = V_{IH}$ or V_{IL}
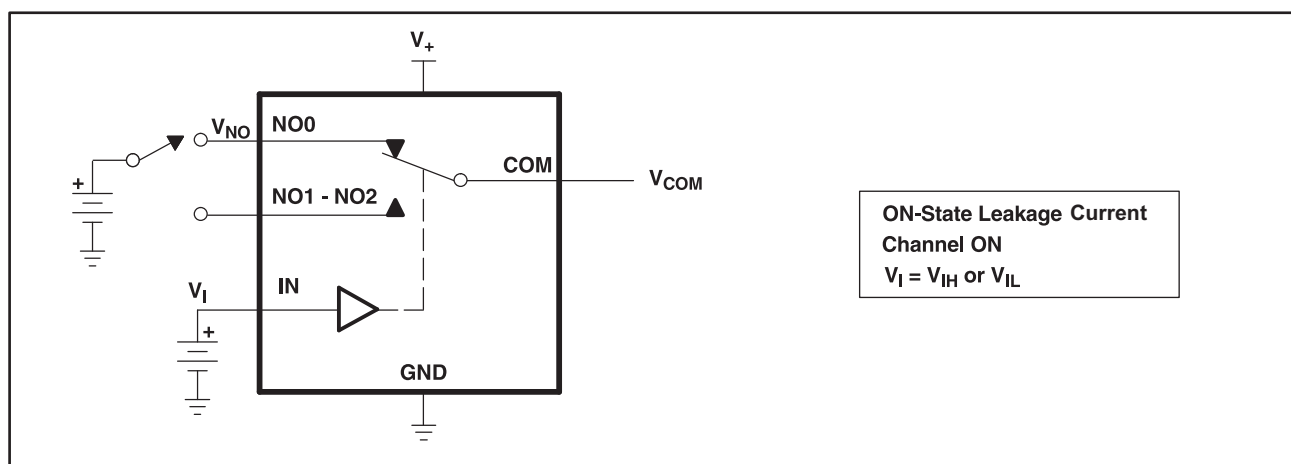
Figure 21. ON-State Leakage Current ($I_{COM(ON)}$, $I_{NO(ON)}$)

Product Folder Link(s): TS5A3359

TEXAS INSTRUMENTS
www.ti.com

TS5A3359
1-Ω SP3T ANALOG SWITCH
5-V/3.3-V SINGLE-CHANNEL 3:1 MULTIPLEXER/DEMULTIPLEXER
SCDS214C−OCTOBER 2005−REVISED JANUARY 2008

PARAMETER MEASURMENT INFORMATION (continued)

Figure 22. Capacitance (C_I, C_COM(ON), C_NO(OFF), C_COM(OFF), C_NO(ON))
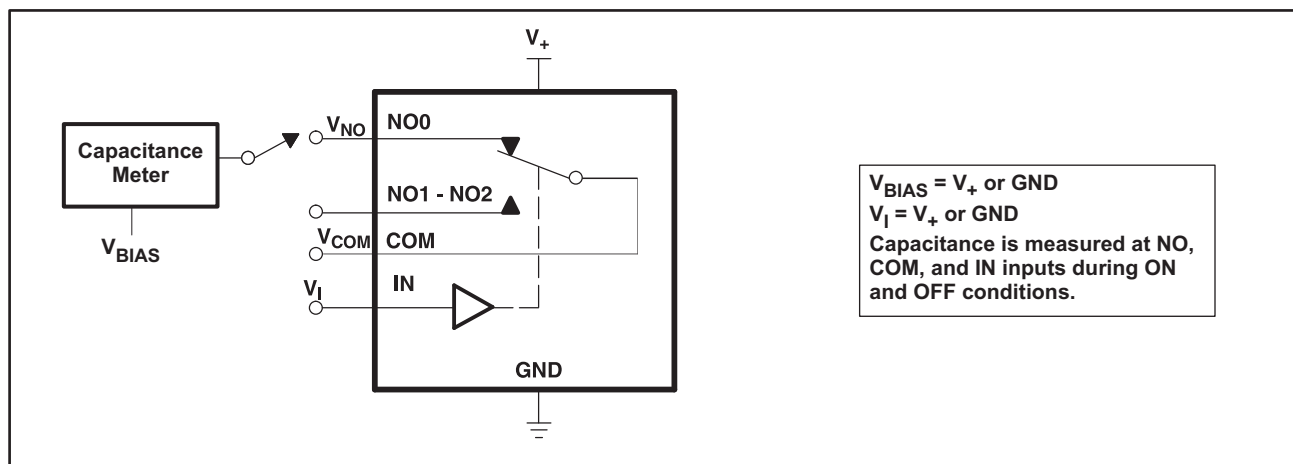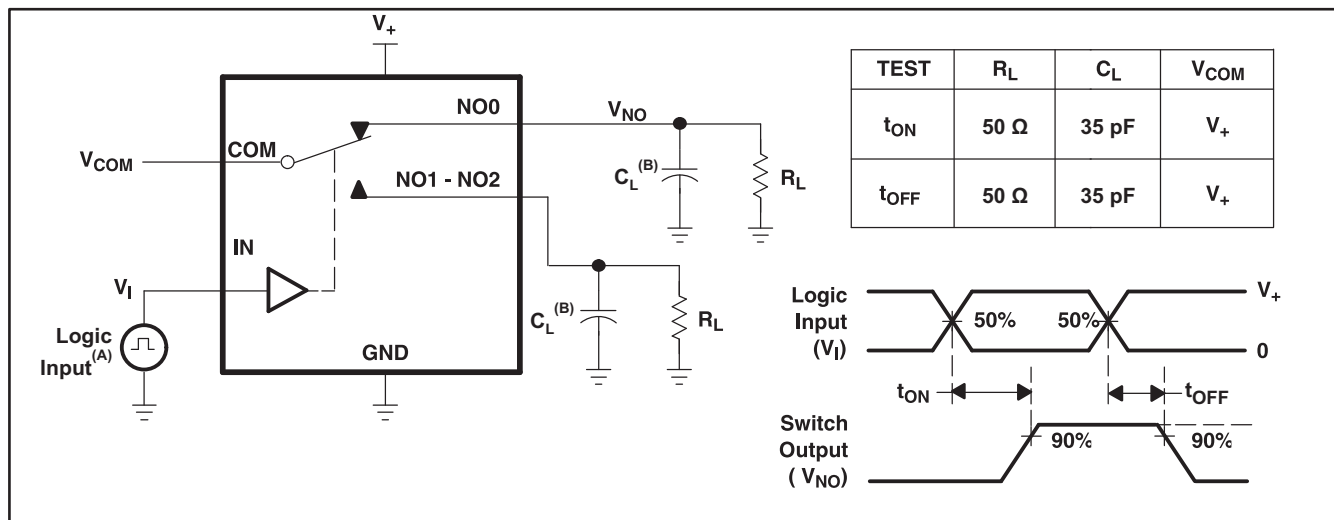
$$\text{Figure 22. Capacitance } (C_I, C_{COM(ON)}, C_{NO(OFF)}, C_{COM(OFF)}, C_{NO(ON)})$$

A. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, ZO = 50 Ω, t_r < 5 ns, t_f < 5 ns.

B. C_L includes probe and jig capacitance.

Figure 23. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})
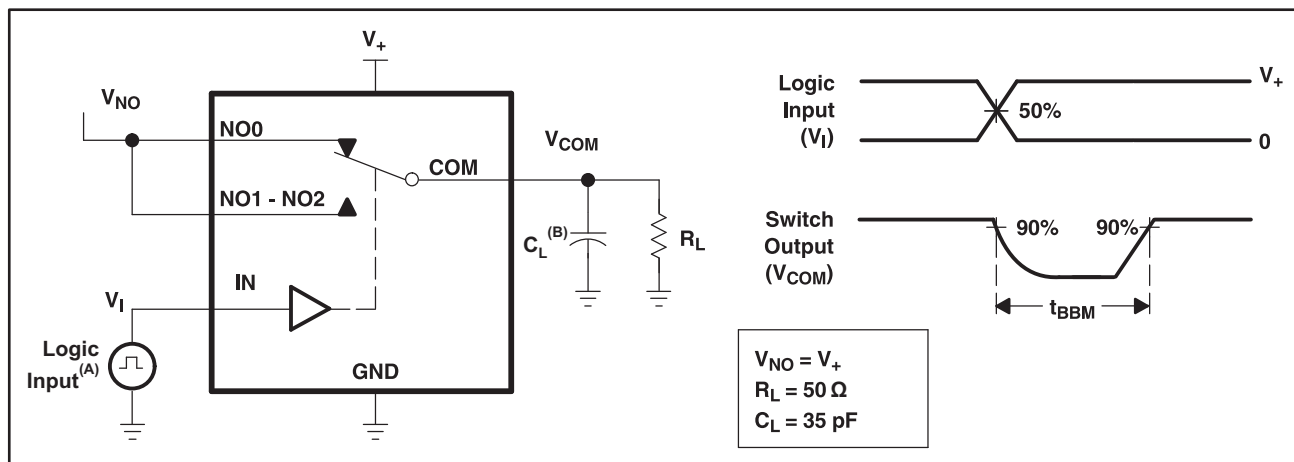
TS5A3359
1-Ω SP3T ANALOG SWITCH
5-V/3.3-V SINGLE-CHANNEL 3:1 MULTIPLEXER/DEMULTIPLEXER
SCDS214C−OCTOBER 2005−REVISED JANUARY 2008

TEXAS INSTRUMENTS
www.ti.com

PARAMETER MEASURMENT INFORMATION (continued)

A. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, ZO = 50 Ω, t_r < 5 ns, t_f < 5 ns.

B. C_L includes probe and jig capacitance.

Figure 24. Break-Before-Make Time (t_{BBM})

Figure 25. Bandwidth (BW)

Product Folder Link(s): *TS5A3359*
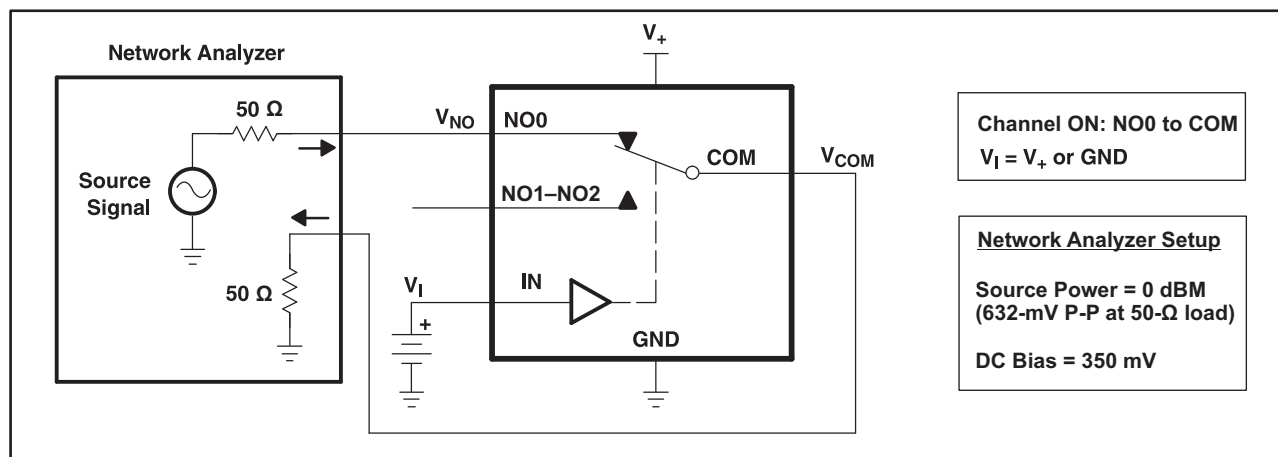
PARAMETER MEASURMENT INFORMATION (continued)
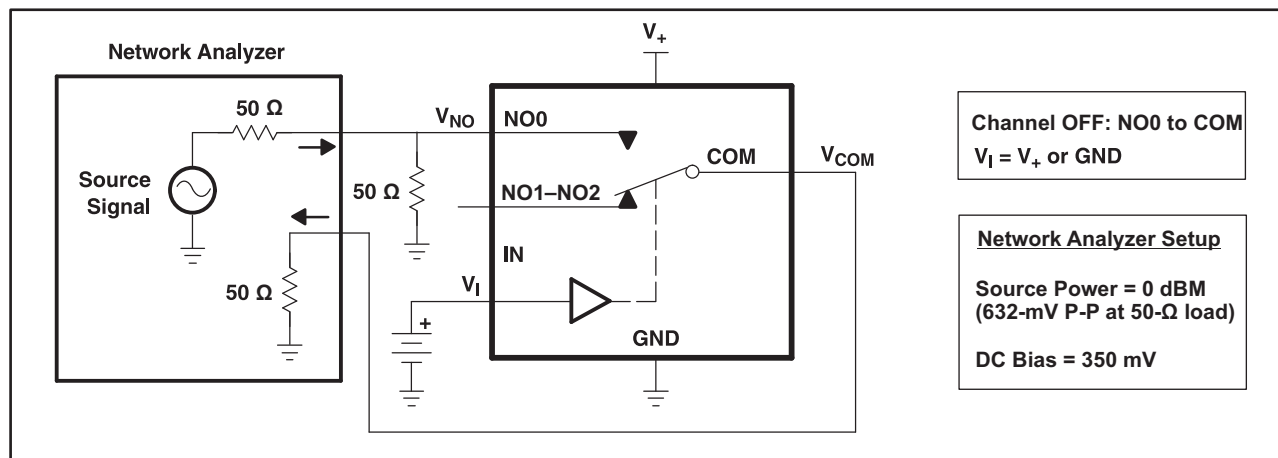
Figure 26. OFF Isolation (O$_{ISO}$)
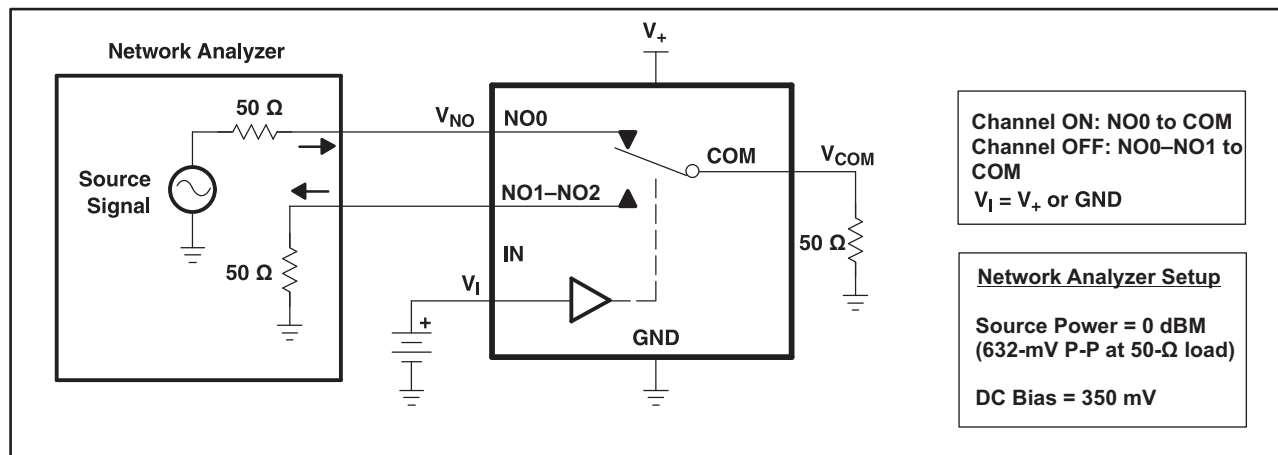
Figure 27. Crosstalk (X$_{TALK}$)

PARAMETER MEASURMENT INFORMATION (continued)
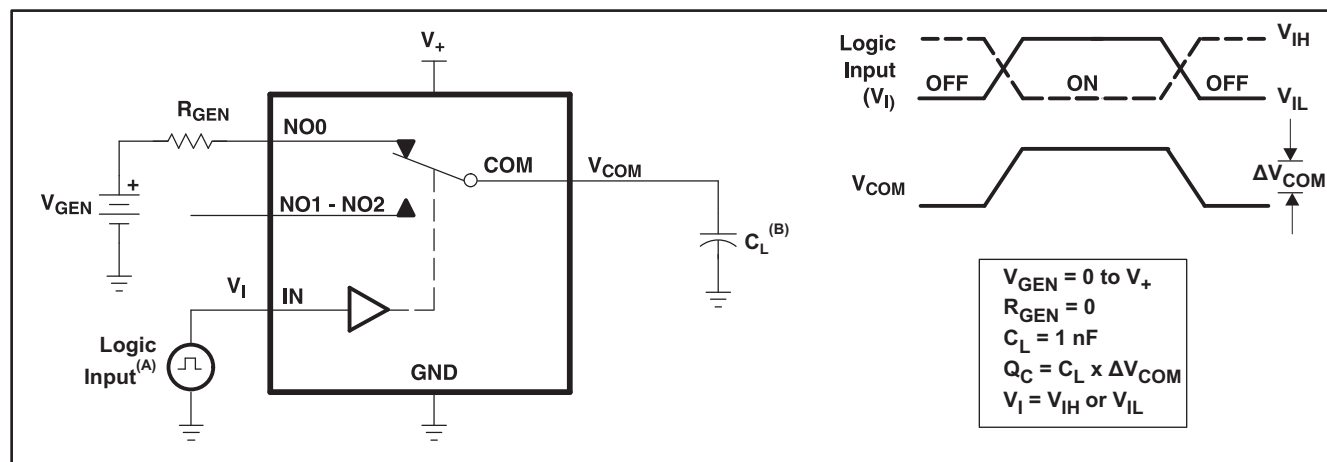
A. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, ZO = 50 Ω, t_r < 5 ns, t_f < 5 ns.

B. C_L includes probe and jig capacitance.

Figure 28. Charge Injection (Q_C)
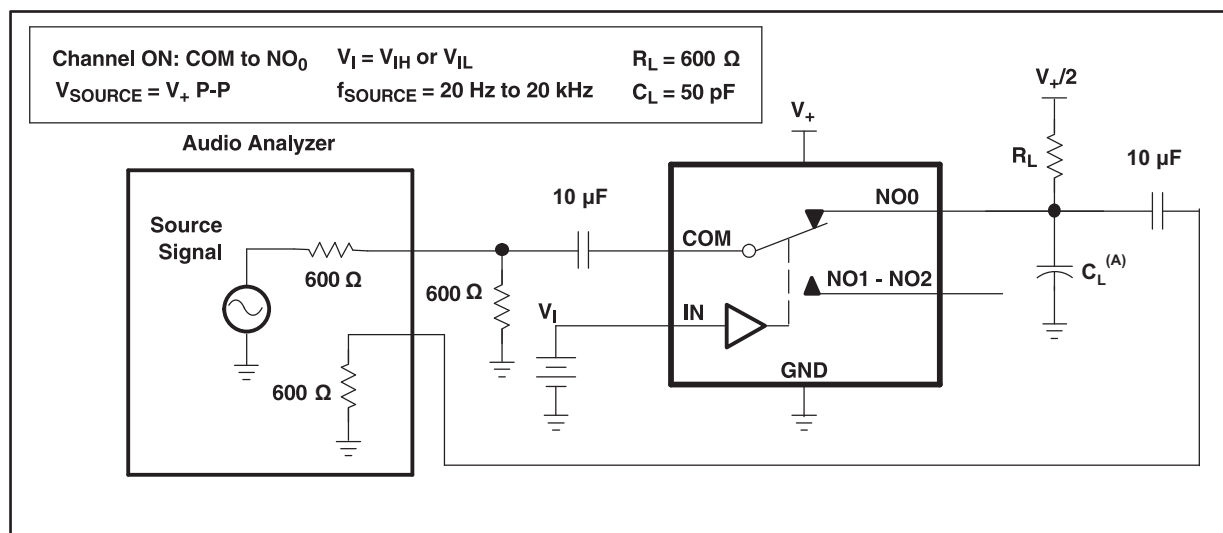
A. C_L includes probe and jig capacitance.

Figure 29. Total Harmonic Distortion (THD)

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TS5A3359DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(AL ~ JALR) JZ	Samples
TS5A3359DCURE4	ACTIVE	US8	DCU	8		TBD	Call TI	Call TI	-40 to 85		Samples
TS5A3359DCURG4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(AL ~ JALR) JZ	Samples
TS5A3359DCUT	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(AL ~ JALR) JZ	Samples
TS5A3359DCUTE4	ACTIVE	US8	DCU	8		TBD	Call TI	Call TI	-40 to 85		Samples
TS5A3359DCUTG4	ACTIVE	US8	DCU	8	250	TBD	Call TI	Call TI	-40 to 85	(AL ~ JALR) JZ	Samples
TS5A3359YZPR	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	J97	Samples
TS5A3359YZPRB	OBSOLETE	DSBGA	YZP	8		TBD	Call TI	Call TI		J97	

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS5A3359DCUR	US8	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3

![Texas Instruments logo] **PACKAGE MATERIALS INFORMATION**

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS5A3359DCUR	US8	DCU	8	3000	202.0	201.0	28.0

DCU (R−PDSO−G8)   PLASTIC SMALL−OUTLINE PACKAGE (DIE DOWN)

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
D. Falls within JEDEC MO−187 variation CA.

4200503/F 07/05

DCU (S−PDSO−G8)   PLASTIC SMALL OUTLINE PACKAGE (DIE DOWN)
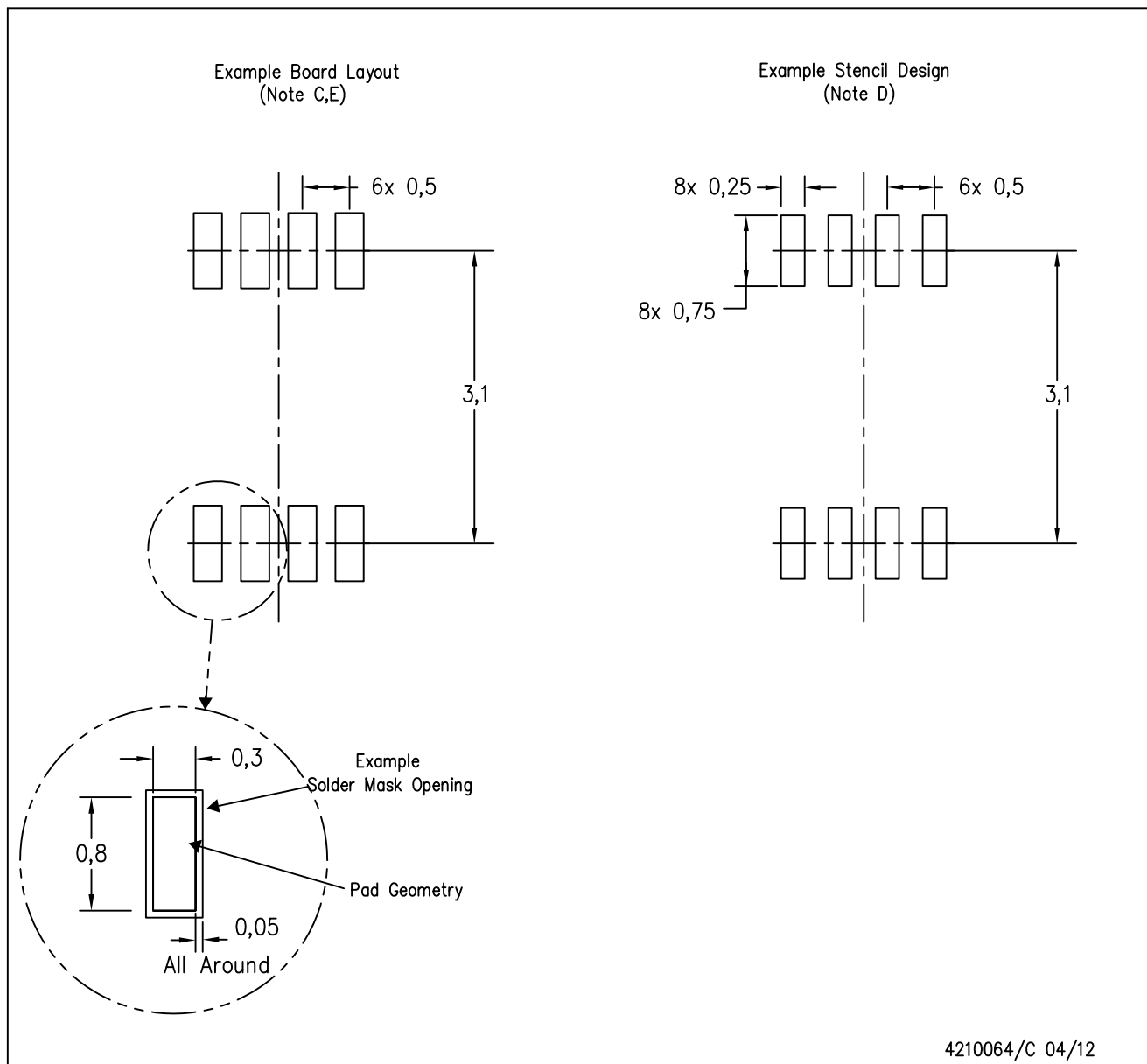
Example Board Layout
(Note C,E)

Example Stencil Design
(Note D)

6x 0,5

8x 0,25

8x 0,75

6x 0,5

3,1

3,1

0,3

Example
Solder Mask Opening

0,8

Pad Geometry

0,05

All Around

4210064/C 04/12

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC−7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC−7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

TEXAS
INSTRUMENTS
www.ti.com

YZP (R−XBGA−N8)   DIE−SIZE BALL GRID ARRAY

E

A

D

Ball A1 Index Area

0,50

0,25

D
C
B
A

1   2

Bottom View

0,25

1,50

0,50

8X ⌀ $\frac{0,25}{0,21}$

⌖ ⌀ 0,015 Ⓜ C A B

0,50 Max

0,05 C

Seating Plane

$\frac{0,19}{0,15}$

C

D: Max = 1.918 mm, Min =1.858 mm

E: Max = 0.918 mm, Min =0.858 mm

4204741−5/M   11/13
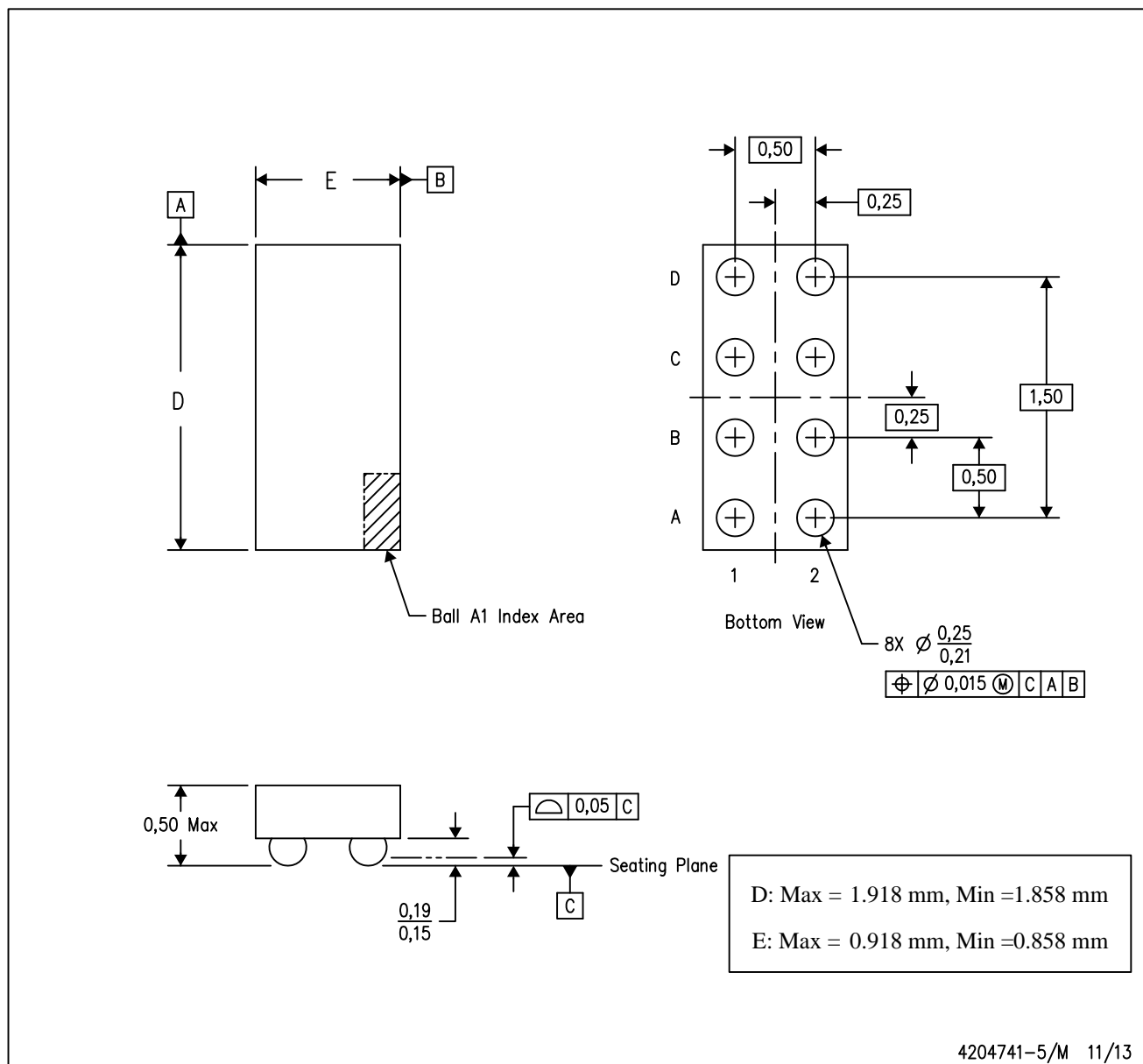
NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M−1994.
        B. This drawing is subject to change without notice.
        C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.

TEXAS
INSTRUMENTS
www.ti.com

IMPORTANT NOTICE

Products		Applications	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Applications Processors	www.ti.com/omap	**TI E2E Community**	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconnectivity		